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December 2013

FQPF9N50CF

N-Channel QFET® FRFET® MOSFET

500 V, 9 A, 850 mΩ

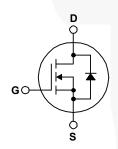
Description

This N-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, active power factor correction (PFC), and • Fast Recovery Body Diode (Typ. 100 ns) electronic lamp ballasts.

Features

- 9 A, 500 V, $R_{DS(on)}$ = 850 m Ω (Max.) @ V_{GS} = 10 V, I_D = 4.5 A
- Low Gate Charge (Typ. 28 nC)
- Low Crss (Typ. 24 pF)
- 100% Avalanche Tested





Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol	Parameter	FQPF9N50CF	Unit	
V _{DSS}	Drain-Source Voltage	500	V	
I _D	Drain Current - Continuous (T _C = 25°C)	9*	Α	
	- Continuous (T _C = 100°C)	5.4*	Α	
I _{DM}	Drain Current - Pulsed (Note	1) 36*	Α	
V _{GSS}	Gate-Source Voltage	± 30	V	
E _{AS}	Single Pulsed Avalanche Energy (Note	2) 360	mJ	
I _{AR}	Avalanche Current (Note	1) 9	Α	
E _{AR}	Repetitive Avalanche Energy (Note	1) 4.4	mJ	
dv/dt	Peak Diode Recovery dv/dt (Note	3) 4.5	V/ns	
P _D	Power Dissipation (T _C = 25°C)	44	W	
	- Derate above 25°C	0.35	W/°C	
T _J , T _{STG}	Operating and Storage Temperature Range	-55 to +150	°C	
T _L	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds.	300	°C	

^{*} Drain current limited by maximum junction temperature

Thermal Characteristics

Symbol	Parameter	FQPF9N50CF	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max. 2.86		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient, Max. 62.5		- 0/00

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FQPF9N50CF	FQPF9N50CF	TO-220F	Tube	N/A	N/A	50 units

Electrical Characteristics $T_C = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Test Conditions		Тур.	Max.	Unit
Off Charac	teristics					
BV _{DSS}	Drain-Source Breakdown Voltage	V_{GS} = 0 V, I_{D} = 250 μ A	500			V
ΔBV_{DSS} / ΔT_{J}	Breakdown Voltage Temperature Coefficient	I_D = 250 μA, Referenced to 25°C		0.57		V/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 500 V, V _{GS} = 0 V			10	μА
		V _{DS} = 400 V, T _C = 125°C	-		100	μА
I _{GSSF}	Gate-Body Leakage Current, Forward	V _{GS} = 30 V, V _{DS} = 0 V	1		100	nA
I _{GSSR}	Gate-Body Leakage Current, Reverse	V _{GS} = -30 V, V _{DS} = 0 V	-		-100	nA
On Charac	teristics					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2.0		4.0	
R _{DS(on)}	Static Drain-Source On-Resistance	V _{GS} = 10 V, I _D = 4.5 A	-	0.70	0.85	Ω
9 _{FS}	Forward Transconductance	V _{DS} = 40 V, I _D = 4.5 A	-	6.5		S
Dynamic C	haracteristics					
C _{iss}	Input Capacitance	V _{DS} = 25 V, V _{GS} = 0 V,		790	1030	p [
C _{oss}	Output Capacitance	f = 1.0 MHz	1	130	170	pF
C _{rss}	Reverse Transfer Capacitance		-	24	30	pF
Switching (Characteristics					
t _{d(on)}	Turn-On Delay Time	V _{DD} = 250 V, I _D = 9A,		18	45	ns
t _r	Turn-On Rise Time	$R_G = 25 \Omega$	-	65	140	ns
t _{d(off)}	Turn-Off Delay Time		-	93	195	ns
t _f	Turn-Off Fall Time	(Note 4)		64	125	ns
Qg	Total Gate Charge	V _{DS} = 400 V, I _D = 9A,	-	28	35	nC
Q _{gs}	Gate-Source Charge	V _{GS} = 10 V	-	4		nC
Q _{gd}	Gate-Drain Charge	(Note 4)	/	15		nC
Drain-Sour	ce Diode Characteristics and Maximum Ratings	5	l.		7	
I _S	Maximum Continuous Drain-Source Diode Forward Current				9*	Α
I _{SM}	Maximum Pulsed Drain-Source Diode Forward Current		-		36*	Α
V _{SD}	Drain-Source Diode Forward Voltage	V _{GS} = 0 V, I _S = 9 A		/	1.4	V
t _{rr}	Reverse Recovery Time	V _{GS} = 0 V, I _S = 9 A,		100		ns
Q _{rr}	Reverse Recovery Charge	dl _F / dt = 100 A/μs		0.3	/	μС

NOTES:

^{1.} Repetitive rating : pulse-width limited by maximum junction temperature.

^{2.} L = 8 mH, I $_{AS}$ = 9 A, V $_{DD}$ = 50 V, R $_{G}$ = 25 Ω , starting T $_{J}$ = 25°C.

 $^{3.~}I_{SD} \leq 11~A,~di/dt \leq 200~A/\mu s,~V_{DD} \leq BV_{DSS,}~Starting~~T_J = 25^{\circ}C.$

^{4.} Essentially independent of operating temperature.

Typical Performance Characteristics

Figure 1. On-Region Characteristics

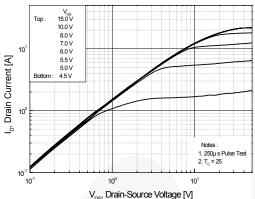
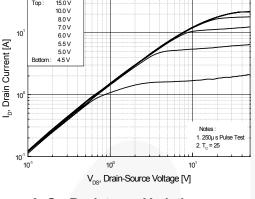


Figure 3. On-Resistance Variation vs. **Drain Current and Gate Voltage**

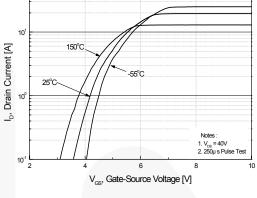


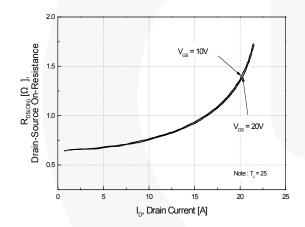
V_{ss}, Gate-Source Voltage [V] Figure 4. Body Diode Forward Voltage

and Temperatue

Variation vs. Source Current

Figure 2. Transfer Characteristics





Reverse Drain Current [A] Notes: 1. V_{cs} = 0V 2. 250µ s Pulse Test 10⁻¹ L 0.2 1.2 V_{SD}, Source-Drain voltage [V]

Figure 5. Capacitance Characteristics

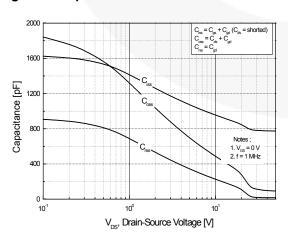
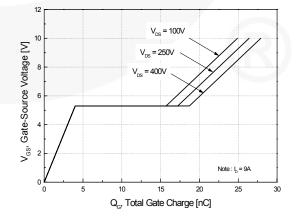


Figure 6. Gate Charge Characteristics



Typical Performance Characteristics (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

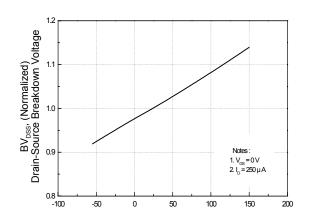


Figure 8. On-Resistance Variation vs. Temperature

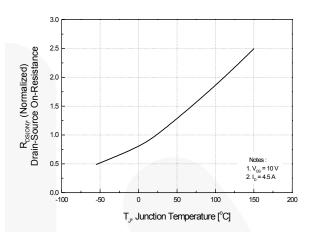


Figure 9. Maximum Safe Operating Area

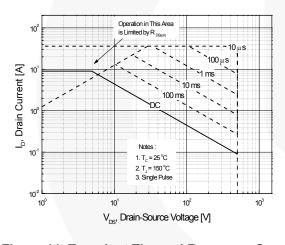


Figure 10. Maximum Drain Current vs. Case Temperature

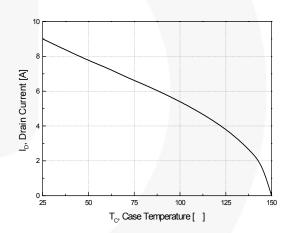
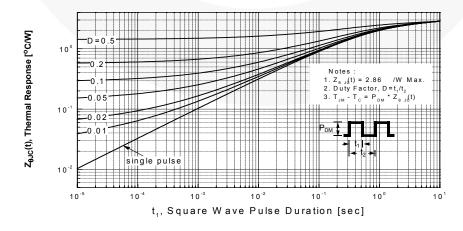


Figure 11. Transient Thermal Response Curve



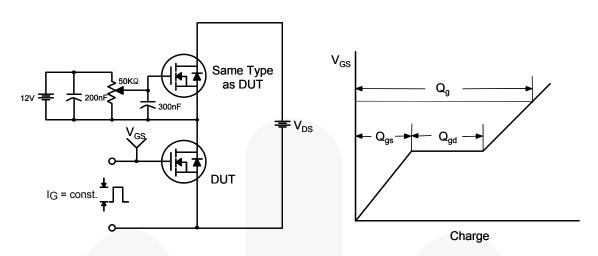


Figure 12. Gate Charge Test Circuit & Waveform

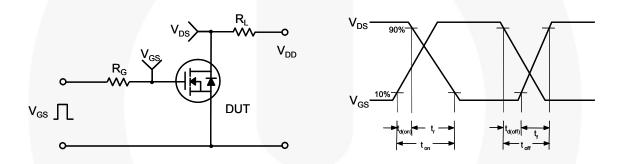


Figure 13. Resistive Switching Test Circuit & Waveforms

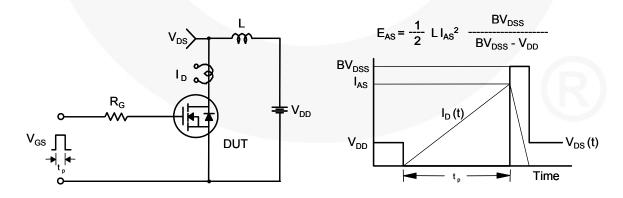


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms

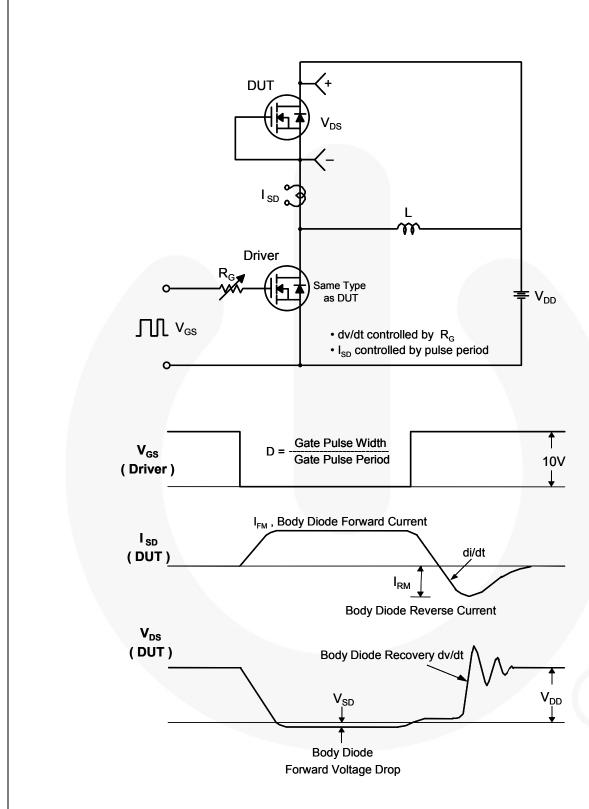


Figure 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms

Mechanical Dimensions

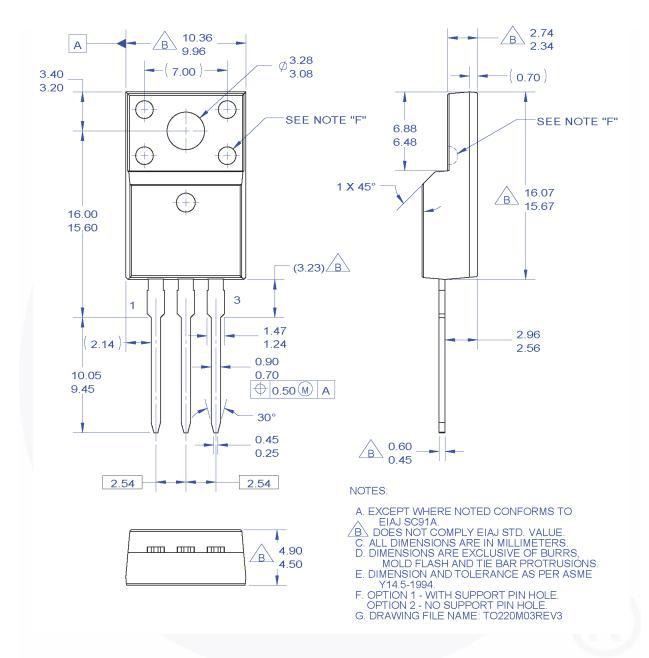


Figure 16. TO220, Molded, 3-Lead, Full Pack, EIAJ SC91, Straight Lead

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